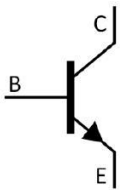


Rev.F Mar.-2016

TO-126 NPN Silicon NPN transistor in a TO-126 Plastic Package.

V_{CEO}
High V_{CEO} Large DC current, high f_T , low $V_{CE(sat)}$.

Low power audio amplifier, high speed switching applications.

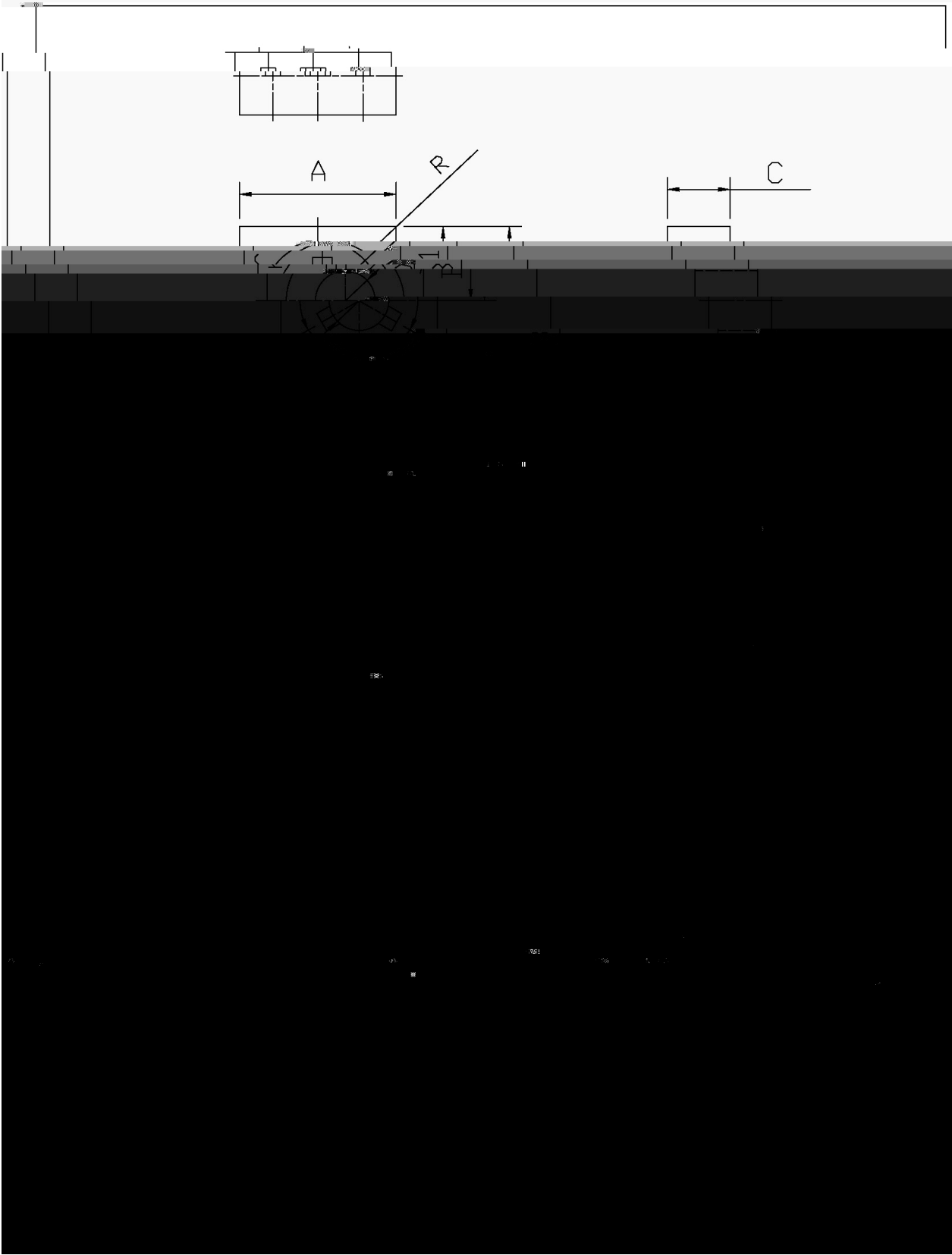


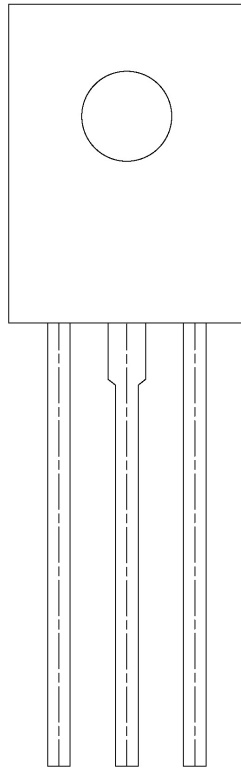
PIN1 Emitter PIN 2

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	100	V
Collector to Emitter Voltage	V_{CEO}	100	V
Emitter to Base Voltage	V_{EBO}	7.0	V

T□-126

单位: mm



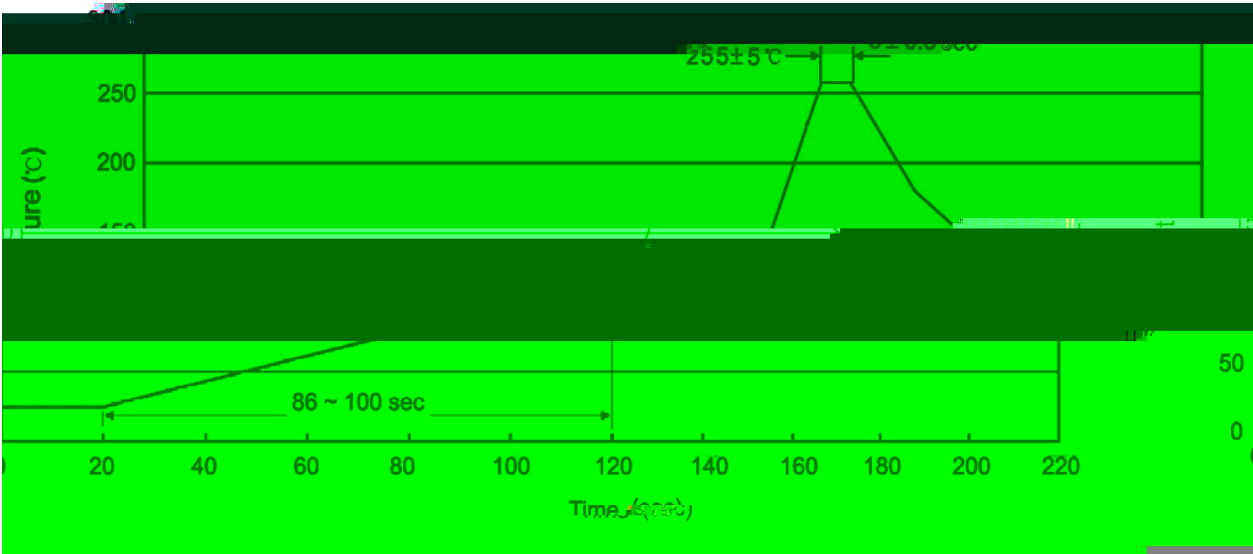


BR

MJE243

Note:

BR:



- Note:

1

25 150

60 90sec;

2

255±5

5±0.5sec;

3

2 10 /sec.
- 1.Preheating:25~150 , Time:60~90sec.

2.Peak Temp.:255±5 , Duration:5±0.5sec.

3. Cooling Speed: 2~10 /sec.

270±5

10±1 sec.

Temp.:270±5

Time:10±1 sec

/ BULK

Package Type	Units			Dimension	(unit mm ³)